NSN 5962-01-310-4811

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-310-4811

Body Length: 2.435 inches

Body Width:

Between 0.510 inches and 0.620 inches

Body Height:

Between 0.165 inches and 0.210 inches

Maximum Power Dissipation Rating:

1.5 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and static operation and monolithic and bidirectional

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

44 input

Case Outline Source And Designator:

D-14 mil-m-38510

Current Rating Per Characteristic:

50.00 milliamperes forward current, peak total value not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

48 printed circuit

Shelf Life:

N/a

Unit Of Measure:

NSN 5962-01-310-4811

Memory Microcircuit - Page 2 of 2

Demilitarization:

No

Fiig:

A458a0

